

Metastable eutectic in Pb-free joints between Sn-3.5Ag and Ni-based substrates

S.A. Belyakov*, C.M. Gourlay

Department of Materials, Imperial College, London SW7 2AZ, United Kingdom

Abstract:

Microstructure development in solder joints between Sn-3.5Ag and Ni-based substrates has been widely reported. However, in the present study we illustrate a new phenomenon: that during soldering of Sn-3.5Ag to Ni or ENIG (electroless nickel, immersion gold), the bulk solder solidifies to contain a metastable eutectic consisting of $\beta\text{Sn}+\text{Ag}_3\text{Sn}+\text{NiSn}_4$ instead of the $\beta\text{Sn}+\text{Ag}_3\text{Sn}+\text{Ni}_3\text{Sn}_4$, expected of equilibrium solidification. It is shown that metastable NiSn_4 coarsens and then decomposes into Ni_3Sn_4 and βSn during ageing at 150 and 200°C and that coarsened NiSn_4 deteriorate impact shear properties.

Keywords: microstructure, intermetallic compounds, eutectic solidification, lead-free solder, electronic packaging, aging

Introduction:

Sn-3.5wt%Ag is a common solder to ENIG surface finish or Ni-based UBMs (underbump metallisations) and it is a popular choice for consumer, automotive and power electronics [1]. Various reports in the literature describe metastable Ni-Sn intermetallics (e.g. NiSn_3 [2-8] or NiSn_4 [9-14]) that form in as-reflowed [6] and thermally-cycled Sn/Ni solder joints [11], in Sn/Ni electroplated couples [2-4, 7, 8] and reaction couples under current stressing [5]. It is important to note that these metastable phases are reported to occur in the reaction layer between the solder and substrate and usually in the solid state. Recently, we have shown that metastable NiSn_4 also forms during eutectic solidification of binary Sn-Ni alloys [12-14]. We note that no papers report the growth of this metastable eutectic during solidification of industrially-important solder-substrate combinations. For example, in the case of Sn-3.5Ag joints on Ni-based substrates, βSn grain microstructure and its evolution during thermal loading are widely reported [15, 16], and a large body of research has been devoted to the interfacial reactions between Sn-3.5Ag and ENIG substrates during solder joint manufacturing and during ageing

at elevated temperatures [15-18]. However, no reports describe metastable NiSn_4 phase formation in these systems during solidification. Since there is negligible solubility of Ni in Ag_3Sn and βSn [15, 19], it is likely that Ni dissolved from the substrate will form Ni_xSn_y intermetallic in the bulk solder in addition to in the interfacial layer. Therefore, it seems surprising that past work has not reported on Ni_xSn_y intermetallics in the bulk solder and whether they are stable Ni_3Sn_4 or metastable $\text{NiSn}_4/\text{NiSn}_3$. The aims of the present study were (i) to explore whether metastable NiSn_4 forms during the solidification of industrially-important Sn-3.5Ag/Ni or /ENIG solder joints and, if so to (ii) investigate the decomposition of metastable NiSn_4 during artificial ageing.

Experimental Methods:

Ni and ENIG-coated Cu substrates were produced from 0.5mm thickness sheet of 99.9Ni or 99.9Cu. ENIG plating yielded a $\sim 5\mu\text{m}$ Ni-P layer (16at%P) and a $0.06\mu\text{m}$ Au layer. Coupons of 10 x 10 mm were cut from the sheets and $100\mu\text{m}$ Sn-3.5Ag solder preforms were placed on the substrates above RM5 flux cream. Reflow soldering was conducted with a heating rate of 1 K/s, time above Sn-Ag eutectic temperature of ~ 80 s, peak temperature of 250°C and a cooling rate of 3 K/s. Joints were subjected to solid-state heat treatments at 150°C and 220°C for up to three months. Microstructure characterisation was conducted in a Zeiss Auriga scanning electron microscope with an INCA x-sight energy dispersive X-ray (EDX) detector and Bruker electron backscattered diffraction (EBSD) detector.

Results and Discussion:

Figure 1 shows a typical cross-section from a Sn-3.5Ag/Ni joint at a range of magnifications. Figure 1A is a schematic of the whole joint for scale. Figure 1B is from an area similar to the rectangle in Figure 1A. A Ni_3Sn_4 -layer is present at the interface with the Ni substrate and the microstructure in the bulk solder is comprised of βSn dendrites surrounded by a eutectic mixture. Note that the βSn matrix has been selectively etched from the surface to improve the imaging of the eutectic morphology. Figures 1C and 1D depict the eutectic region in more detail. Two distinct morphologies can be differentiated: (i) rod-like and (ii) sheet-like eutectic phases. With EDX, the rod-like eutectic phase was found to correspond to Ag_3Sn and the sheet-like eutectic phase has the composition close to NiSn_4 (Table 1).

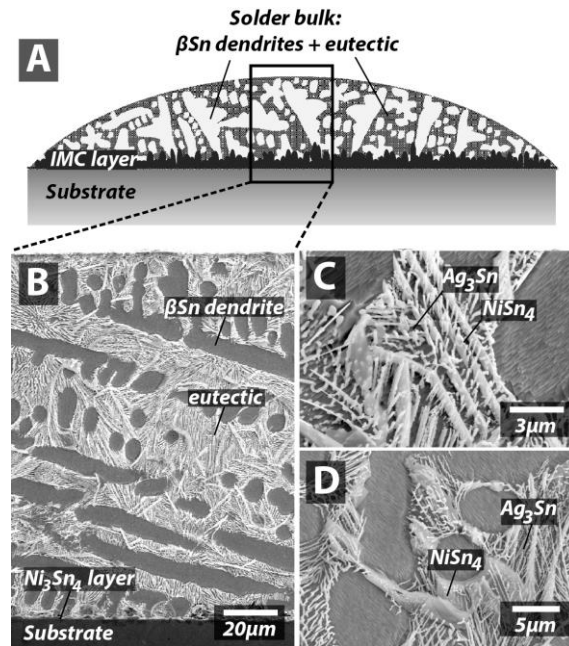


Figure 1. (A): schematic solder joint cross-section, (B,C,D): microstructures of as-soldered Sn-3.5Ag/Ni joints at different magnifications, β Sn was selectively removed.

Table 1. SEM-EDX measurements of the eutectic intermetallics in as-soldered Sn-3.5Ag/Ni and Sn-3.5Ag/ENIG solder joints.

	Sn, at%	Ni, at%	Au, at%	Ag, at%	Proposed phase
Sn-3.5Ag/Ni solder joints					
Mean	81.2	18.8	-	-	NiSn₄
St. dev.	0.78	0.78	-	-	
Mean	24.9	-	-	75.1	Ag₃Sn
St. dev.	0.56	-	-	0.56	
Sn-3.5Ag/ENIG solder joints					
Mean	81.9	12.3	5.8	-	(Ni,Au)Sn₄
St. dev.	0.94	0.94	1.34	-	
<i>At least 10 particles were measured for each phase</i>					

The identity of the intermetallics was further confirmed by EBSD, where the NiSn₄ EBSD patterns (Figure 2B) could only be indexed as oC20-NiSn₄ phase (Figure 2D), consistent with NiSn₄ being isomorphous to PdSn₄, PtSn₄ and AuSn₄ [20]. Note that the NiSn₄ has a very similar sheet-like morphology to the eutectic NiSn₄ in binary Sn-Ni alloys [12, 13]. Table 1 also shows no Ag solubility in NiSn₄ and no Ni was detected in Ag₃Sn. Examination of microstructures revealed that some eutectic

regions contained only $\beta\text{Sn} + \text{Ag}_3\text{Sn}$ whilst others contained $\beta\text{Sn} + \text{Ag}_3\text{Sn} + \text{NiSn}_4$. Since this is three-component solidification, it can be inferred that the solidification sequence was: (i) $L \rightarrow \beta\text{Sn}$ primary dendrite growth (Figure 1B), followed by (ii) $L \rightarrow \beta\text{Sn} + \text{Ag}_3\text{Sn}$ univariant eutectic growth and finally (iii) $L \rightarrow \beta\text{Sn} + \text{Ag}_3\text{Sn} + \text{NiSn}_4$ invariant eutectic growth; i.e. the NiSn_4 formed in a ternary eutectic reaction during the latest solidification stages.

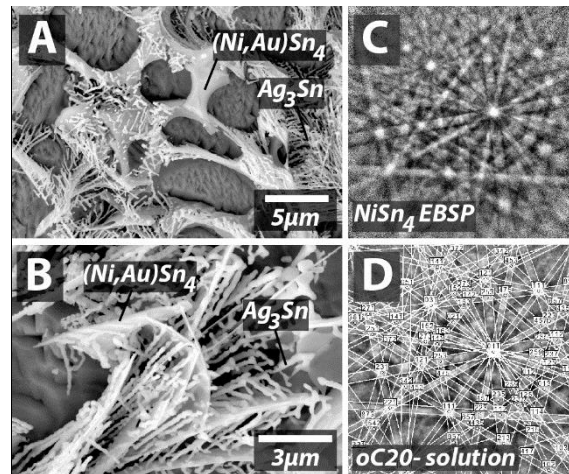


Figure 2. Eutectic microstructures of as-soldered (A,C) Sn-3.5Ag/ENIG joints, βSn was selectively removed; (B): representative EBSD from NiSn_4 eutectic and (D): solution of EBSD in (B) as oC20- NiSn_4 .

Figures 2(A) and (B) show typical eutectic regions in as-soldered Sn-3.5Ag/ENIG joints. Similar to soldering to Ni, there are two distinct intermetallic phases in the eutectic: a rod-like and a sheet-like phase. The EDX results in Table 1 show that the sheet-like phase has composition consistent with $(\text{Ni,Au})\text{Sn}_4$ and contains approximately twice as much Ni as Au. EBSD patterns similar to Figure 2(C) could only be indexed as oC20- NiSn_4 or isotypic AuSn_4 , PdSn_4 or PtSn_4 . The presence of Au in Sn-3.5Ag/ENIG solder joints added extra complexity to the system. The EDX results in Table 1 suggest that most dissolved Au segregated to NiSn_4 because no Au was detected in the βSn matrix, Ag_3Sn or Ni_3Sn_4 interfacial layer. The volume fraction of NiSn_4 eutectic sheets was noticeably higher in Sn-3.5Ag/ENIG than Sn-3.5Ag/Ni joints as dissolved Au atoms replaced Ni atoms in the NiSn_4 phase up to 6% (Table 1). Other than the increased volume fraction of NiSn_4 eutectic, no major differences were observed for 3.5Ag/Ni and 3.5Ag/ENIG solder joint bulk microstructures. The interfacial zone in ENIG-plated

solder joints contained multiple layers but with Ni_3Sn_4 as the intermetallic on the Sn side, which is consistent with past literature [15, 16].

NiSn_4 is not an equilibrium phase in the Sn-Ag-Ni system [21] and it was found here that NiSn_4 undergoes the following transformation $\text{NiSn}_4 \rightarrow \text{Ni}_3\text{Sn}_4 + \beta\text{Sn}$ with time at 150 and 200°C. Figure 3 (A-B) demonstrates the microstructural changes during ageing of Sn-3.5Ag/Ni joints at 150°C. It was found that NiSn_4 decomposition in Sn-3.5Ag/Ni joints occurs in two stages: (i) coarsening of eutectic NiSn_4 sheets into tile-like NiSn_4 particles up to 20µm in size, similar to that shown in Figure 3C, followed by (ii) $\text{NiSn}_4 \rightarrow \text{Ni}_3\text{Sn}_4 + \beta\text{Sn}$ decomposition. Typical, newly formed Ni_3Sn_4 crystals are shown in Figure 3D.

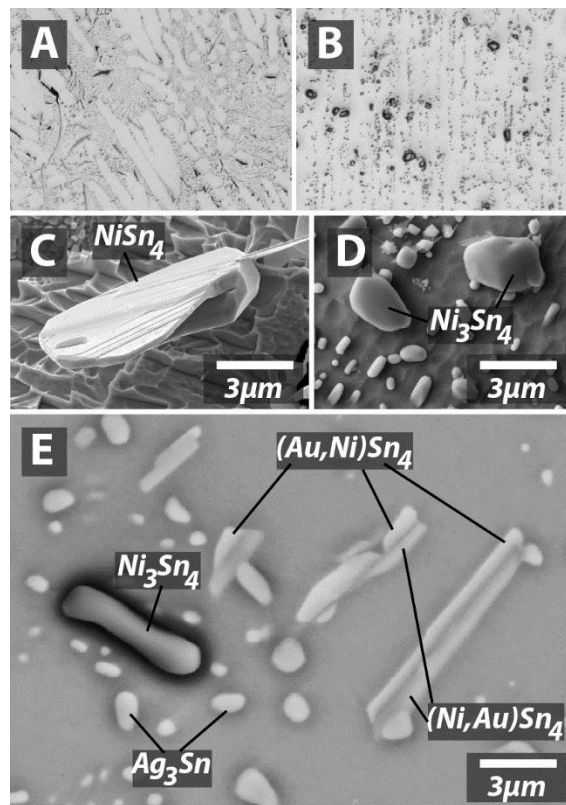


Figure 3. Sn-3.5Ag/Ni solder joint (A): as-soldered and (B): heat treated 1 month at 150°C. (C): coarsened NiSn_4 eutectic particle and (D): Ni_3Sn_4 crystals formed during $\text{NiSn}_4 \rightarrow \text{Ni}_3\text{Sn}_4 + \beta\text{Sn}$ transformation. (E): BSE image depicting $(\text{Ni,Au})\text{Sn}_4 \rightarrow \text{Ni}_3\text{Sn}_4 + \text{AuSn}_4 + \beta\text{Sn}$ transformation during ageing of Sn-3.5Ag/ENIG joints at 150°C

The presence of Au in Sn-3.5Ag/ENIG joints added extra complexity in the NiSn₄ decomposition process. Figure 3E shows that, during ageing at 150°C, the Au separates from coarsening (Ni,Au)Sn₄ particles to form (Au,Ni)Sn₄ attached to the (Ni,Au)Sn₄. As the Au content of (Ni,Au)Sn₄ decreases, it then transforms into Ni₃Sn₄. In the backscattered electron image of Figure 3E Au-rich (Au,Ni)Sn₄ is brighter than Ni-rich (Ni,Au)Sn₄ and Ni₃Sn₄ is the darkest phase. Further micrographs showing microstructure evolution during (Ni,Au)Sn₄ decomposition are given in Supplementary Information Figures SI 2-3. After NiSn₄ transformation, AuSn₄ shortly existed in the bulk as tile-like crystals measuring up to ~2µm in size that then disappeared during prolonged ageing. It is feasible that the Au dissolved into the βSn matrix as, according to the Sn-Au phase diagram [22], βSn can dissolve up to 0.28-0.4wt%Au at the ageing temperatures (150-200°C), which is above the amount of Au dissolved from the 60nm Au layer during soldering. A number of authors [23-25] report on AuSn₄ reprecipitation in the interfacial zone during ageing. This was not observed in the current investigation after three months at 150°C or 200°C, most likely because the Au capping layer on the ENIG used was much thinner than in [23]. The transformation of NiSn₄ or (Au,Ni)Sn₄ eutectic did not go to completion at 150°C in the 3 month time frame of the present study, indicating that decomposition would depend on the working environment of a solder joint and it is highly likely to be ongoing throughout its life. Further work is required to quantify the decomposition kinetics.

Given that joints between Sn-3.5Ag and ENIG have been in widespread industrial use for many years and there are many scientific papers on this solder-substrate combination (e.g. [15-18]), it is surprising that metastable NiSn₄ in the eutectic has not been reported before. One reason may be the difficulty of observing the thin NiSn₄ eutectic sheets in polished cross-sections- we find that selective etching of βSn (such as in Fig.1 and 2) is useful in clearly revealing the eutectic intermetallics. Another reason may be that the presence of Au has clouded the interpretation, with researchers assuming this is AuSn₄ with some dissolved Ni. However, our findings of eutectic NiSn₄ when Sn-3.5Ag is soldered to Ni demonstrates that Au is not necessary for NiSn₄ to form. The nucleation and growth advantages of

metastable NiSn_4 over stable Ni_3Sn_4 are likely to be similar to those discussed previously for the binary Ni-Sn system [12].

Since NiSn_4 grows in a eutectic reaction, it is distributed throughout the whole of the bulk solder (e.g. Figure 1(B)). It is, therefore, natural to ask how metastable NiSn_4 and its decomposition to stable Ni_3Sn_4 influence joint reliability. Figure 4 shows results of impact shear testing of $500\mu\text{m}$ Sn-3.5Ag-0.1Ni solder balls on ENIG substrates. The shear test displacement rate was 100mm/s. It can be seen that coarsened NiSn_4 particles are on the fracture surface indicating that NiSn_4 was involved in crack nucleation and/or propagation. Coarsened NiSn_4 particles seem to act similar to the widely reported embrittlement of solder joints by isomorphous AuSn_4 or PdSn_4 phases [24, 26-28].

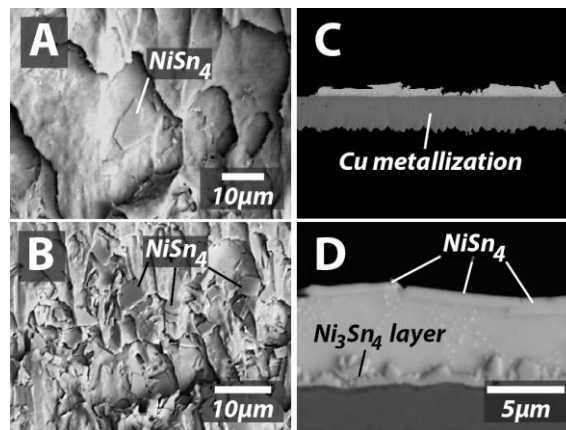


Figure 4. Fracture surfaces of $500\mu\text{m}$ Sn-3.5Ag-0.1Ni solder balls soldered to ENIG. (A), (B): view from above and (C), (D): side view featuring coarsened NiSn_4 particles. Ageing conditions: 1 month at 150°C .

Conclusions:

In summary, where previous research on Sn-3.5Ag/ENIG joints report only the equilibrium phases growing in the system, it has been shown here that the bulk solder solidifies to contain a metastable eutectic consisting of $\beta\text{Sn}+\text{Ag}_3\text{Sn}+\text{NiSn}_4$ instead of the expected $\beta\text{Sn}+\text{Ag}_3\text{Sn}+\text{Ni}_3\text{Sn}_4$. Metastable NiSn_4 has been found to coarsen and then decompose into stable Ni_3Sn_4 during ageing at 150°C and this reaction did not go to completion in 3 months. Additionally, coarsened NiSn_4 was found on the

fracture surface after impact shear testing. These findings point to the need to develop approaches to control eutectic NiSn₄ formation, coarsening and decomposition.

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